Onsemi

PNP Epitaxial Silicon Transistor

KSP92

Description

High Voltage Transistor

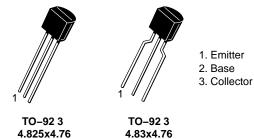
Features

• These Devices are Pb-Free, Halogen Free/BFR Free, Beryllium Free and are RoHS Compliant

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-Base Voltage	-300	V
V _{CEO}	Collector-Emitter Voltage	-300	V
V _{EBO}	Emitter-Base Voltage	-5	V
۱ _C	Collector Current	-500	mA
P _C	Collector Power Dissipation ($T_a = 25^{\circ}C$)	625	mW
	Derate above 25°C	5	mW/°C
P _C	Collector Power Dissipation ($T_C = 25^{\circ}C$)	1.5	W
	Derate above 25°C	12	mW/°C
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55~150	°C

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C, unless otherwise noted)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



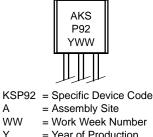
4.825x4.76 CASE 135AN

А

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LEADFORMED CASE 135AR





= Year of Production

ORDERING INFORMATION

Device	Package	Packing Method
KSP92BU	TO-92 3, CASE 135AN	10000 Units / Bulk Bag
KSP92TA	TO-92 3, CASE 135AR	2000 Units / Fan-Fold

ELECTRICAL CHARACTERISTICS ($T_a = 25^{\circ}C$ unless otherwise noted)

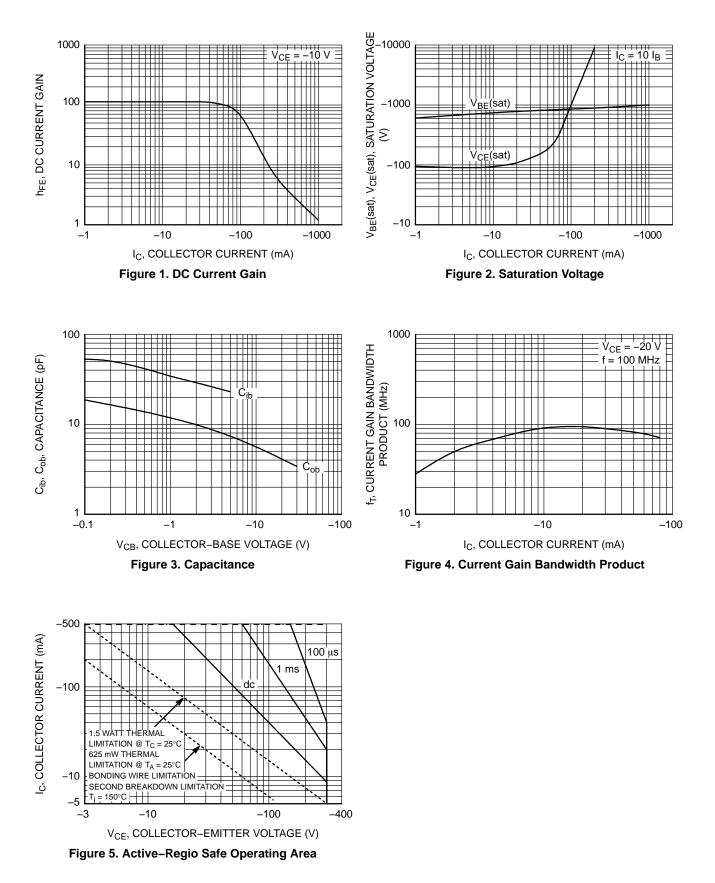
Symbol	Parameter	Test Condition	Min	Max	Unit
BV _{CBO}	Collector–Base Breakdown Voltage	$I_{\rm C} = -100 \ \mu \text{A}, \ I_{\rm E} = 0$	-300	-	V
BV _{CEO}	* Collector-Emitter Breakdown Voltage	$I_{\rm C} = -1 \text{mA}, I_{\rm B} = 0$	-300	-	V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_{E} = -100 \ \mu A, \ I_{C} = 0$	-5	-	V
I _{CBO}	Collector Cur–off Current	$V_{CB} = -200 \text{ V}, I_E = 0$	-	-0.25	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = -3 V, I_C = 0$	-	-0.10	μΑ
h _{FE}	* DC Current Gain	$V_{CE} = -10 \text{ V}, \text{ I}_{C} = -1 \text{ mA}$ $V_{CE} = -10 \text{ V}, \text{ I}_{C} = -10 \text{ mA}$ $V_{CE} = -10 \text{ V}, \text{ I}_{C} = -30 \text{ mA}$	25 40 25	- - -	
V _{CE} (sat)	*Collector-Emitter Saturation Voltage	$I_{\rm C}$ = -20 mA, $I_{\rm B}$ = -2 mA	-	-0.50	V
V _{BE} (sat)	* Base–Emitter Saturation Voltage	$I_{\rm C} = -20 \text{ mA}, I_{\rm B} = -2 \text{ mA}$	-	-0.90	V
f _T	Current Gain Bandwidth Product	$V_{CE} = -20 \text{ V}, I_{C} = -10 \text{ mA}, f = 100 \text{ MHz}$	50	-	MHz
C _{ob}	Output Capacitance	$V_{CB} = -20 \text{ V}, \text{ I}_{E} = 0, \text{ f} = 1 \text{ MHz}$	-	6	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. *Pulse Test: PW \leq 300 μ s, Duty Cycle \leq 2%.

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KSP92

TYPICAL PERFORMANCE CHARACTERISTICS





onsemi

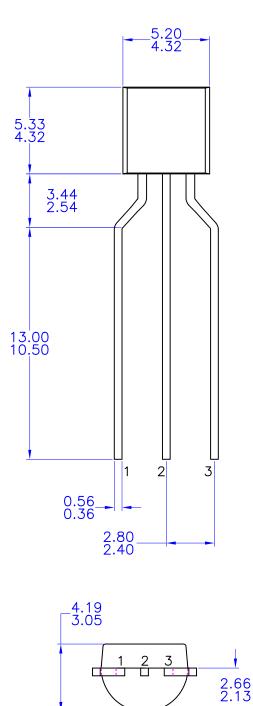
TO-92 3 4.825x4.76 CASE 135AN ISSUE O DATE 31 JUL 2016 _5.20_ ______ 5.33 (0.81) 15.62 2 3 1 0.52 0.56 0.36 1.27 NOTES: UNLESS OTHERWISE SPECIFIED 2.54 A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS. B) ALL DIMENSIONS ARE IN MILLIMETERS. с́э DRAWING CONFORMS TO ASME Y14.5M-2009. 4.19 3.05 2.66 2.13 2 3 1 Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. **DOCUMENT NUMBER:** 98AON13880G **DESCRIPTION:** TO-92 3 4.825X4.76 PAGE 1 OF 1

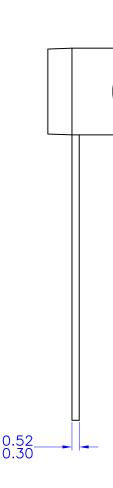
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TO-92 3 4.83x4.76 LEADFORMED CASE 135AR ISSUE O

DATE 30 SEP 2016





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